

NOT RECOMMENDED FOR NEW DESIGN USE DMN65D8LDW



2N7002DWA

Product Summary

BV _{DSS}	R _{DS(ON)}	Package	I _D T _A = +25°C
60V	$8\Omega @ V_{GS} = 5V$ SOT363		170mA
807	6Ω @ V _{GS} = 10V	301303	200mA

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package
- HBM Class 1C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe Solderable per MIL-STD-202, Method 208 (23)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)

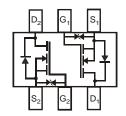
SOT363



HBM Class 1C



Top View



Top View Internal Schematic

Ordering Information (Notes 4 & 5)

Part Number	Compliance	Case	Packaging
2N7002DWA-7	Standard	SOT363	3,000/Tape & Reel
2N7002DWA-13	Standard	SOT363	10,000/Tape & Reel
2N7002DWAQ-7	Automotive	SOT363	3,000/Tape & Reel
2N7002DWAQ-13	Automotive	SOT363	10,000/Tape & Reel

Notes:

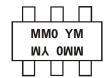
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



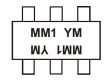
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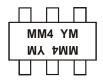
Marking Information



MM0 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017) M = Month (ex: 9 = September)



MM1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017) M = Month (ex: 9 = September)



MM4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

Year	2012	-	20	17	2018	2019	2020	2021	20	22	2023	2024
Code	Z	-			F	G	Н	I		J	K	L
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

	Characteristic			Symbol	Value	Unit
Drain-Source Voltage				V_{DSS}	60	V
Gate-Source Voltage				V _{GSS}	±20	V
Continuous Drain Current (Note 6)	V _{GS} = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	d _l	180 140	mA
Continuous Drain Current (Note 6)	$V_{GS} = 5V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	۵	150 120	mA
Continuous Drain Current (Note 7)	V _{GS} = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	200 160	mA
Continuous Drain Current (Note 7)	V _{GS} = 5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ΙD	170 140	mA
Pulsed Drain Current (10µs Pulse, D	Outy Cycle = 1%)			I _{DM}	700	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P_{D}	300	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	435	°C/W
Total Power Dissipation (Note 7)	P_{D}	400	mW
Thermal Resistance, Junction to Ambient (Note 7)	$R_{ heta JA}$	330	°C/W
Thermal Resistance, Junction to Case (Note 7)	R _e JC	139	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- 6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.



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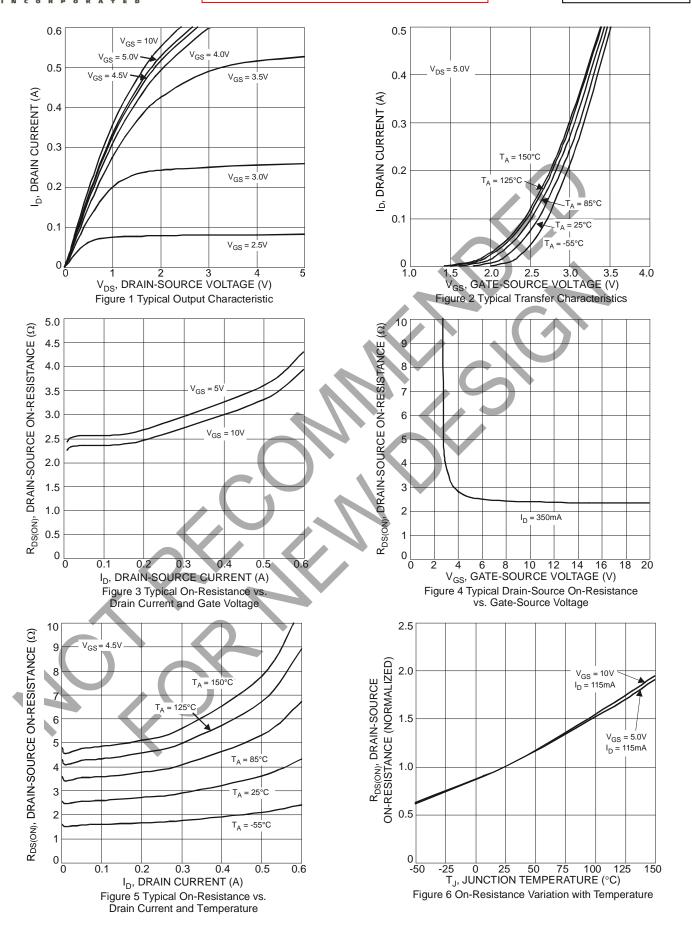
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	I	_	1.0	μΑ	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Body Leakage	I _{GSS}	1	_	±5	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	0.8	_	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance			_	8	Ω	$V_{GS} = 5.0V, I_D = 0.115A$
Static Drain-Source Off-Resistance	R _{DS(ON)}	l	_	6	Ω	$V_{GS} = 10.0V, I_D = 0.115A$
Forward Transconductance	g FS	80	_	_	mS	$V_{DS} = 10V, I_D = 0.115A$
Diode Forward Voltage	V_{SD}		0.8	1.2	V	$V_{GS} = 0V, I_S = 115mA$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	I	22.0	_		
Output Capacitance	Coss	l	3.2		pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	C _{rss}	_	2.0	_		
Gate Resistance	R_{G}	_	88	+	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge V _{GS} = 10V	Q_g	1	0.87			
Total Gate Charge V _{GS} = 4.5V	Q_{g}		0.43	1	nC	$V_{GS} = 10V, V_{DS} = 30V,$
Gate-Source Charge	Q _{gs}	_	0.11	-	TIC	$I_D = 150 \text{mA}$
Gate-Drain Charge	Q_{gd}	_	0.11	_		
Turn-On Delay Time	t _{D(ON)}	_	3.3			
Turn-On Rise Time	t _R	_	3.2	_	ns	$V_{DD} = 30V$, $I_D = 0.115A$, $V_{GEN} = 10V$,
Turn-Off Delay Time	t _{D(OFF)}	J	12.0		115	$R_{GEN} = 25\Omega$
Turn-Off Fall Time	t _F	-	6.3	—		

Notes:

^{8.} Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing.







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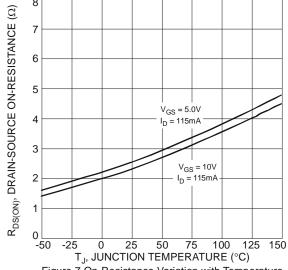
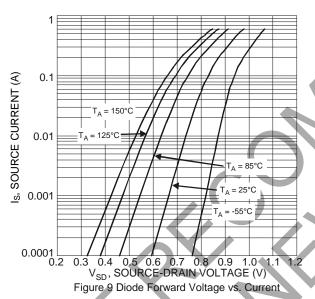


Figure 7 On-Resistance Variation with Temperature



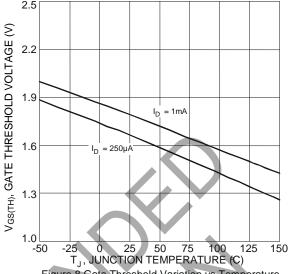
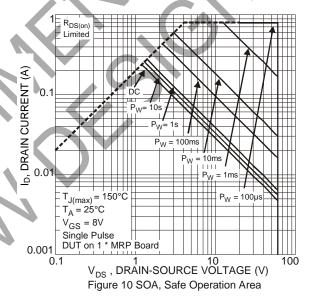


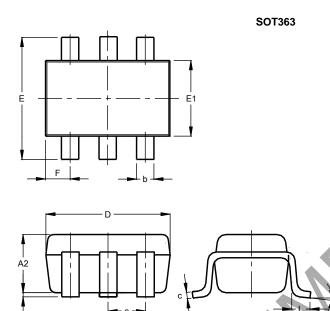
Figure 8 Gate Threshold Variation vs.Temperature





Package Outline Dimensions

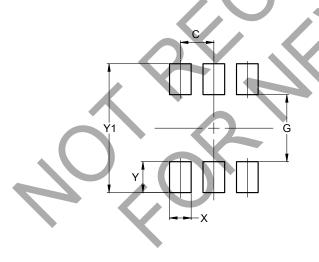
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	1.00				
b	0.10	0.30	0.25				
C	0.10	0.22	0.11				
Ь	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	().650 E	SC				
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
V1	2 500

SOT363



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